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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	Coldfire V4E
Core Size	32-Bit Single-Core
Speed	166MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, SPI, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	99
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.43V ~ 1.58V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	388-BBGA
Supplier Device Package	388-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mcf5482czp166

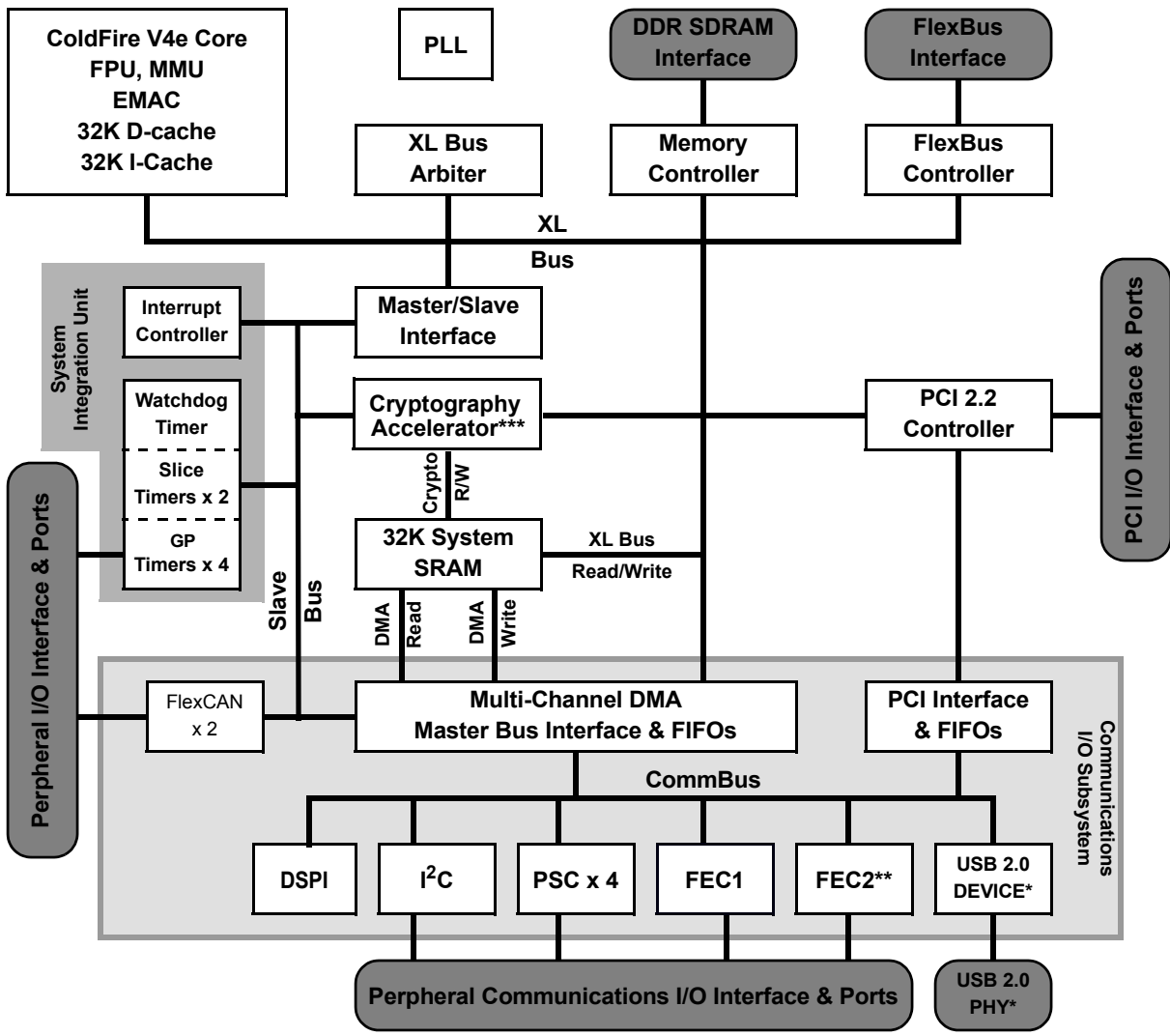


Figure 1. MCF548X Block Diagram

1 Maximum Ratings

Table 1 lists maximum and minimum ratings for supply and operating voltages and storage temperature. Operating outside of these ranges may cause erratic behavior or damage to the processor.

Table 1. Absolute Maximum Ratings

Rating	Symbol	Value	Units
External (I/O pads) supply voltage (3.3-V power pins)	EV_{DD}	-0.3 to +4.0	V
Internal logic supply voltage	IV_{DD}	-0.5 to +2.0	V
Memory (I/O pads) supply voltage (2.5-V power pins)	$SD V_{DD}$	-0.3 to +4.0 SDR Memory -0.3 to +2.8 DDR Memory	V
PLL supply voltage	$PLL V_{DD}$	-0.5 to +2.0	V
Internal logic supply voltage, input voltage level	V_{in}	-0.5 to +3.6	V
Storage temperature range	T_{stg}	-55 to +150	°C

2 Thermal Characteristics

2.1 Operating Temperatures

Table 2 lists junction and ambient operating temperatures.

Table 2. Operating Temperatures

Characteristic	Symbol	Value	Units
Maximum operating junction temperature	T_j	105	°C
Maximum operating ambient temperature	T_{Amax}	<85 ¹	°C
Minimum operating ambient temperature	T_{Amin}	-40	°C

¹ This published maximum operating ambient temperature should be used only as a system design guideline. All device operating parameters are guaranteed only when the junction temperature lies within the specified range.

2.2 Thermal Resistance

Table 3 lists thermal resistance values.

Table 3. Thermal Resistance

Characteristic		Symbol	Value	Unit
324 pin TEPBGA — Junction to ambient, natural convection	Four layer board (2s2p)	θ_{JMA}	20–22 ^{1,2}	°CW
388 pin TEPBGA — Junction to ambient, natural convection	Four layer board (2s2p)	θ_{JMA}	19 ^{1,2}	°CW
Junction to ambient (@200 ft/min)	Four layer board (2s2p)	θ_{JMA}	16 ^{1,2}	°CW
Junction to board	—	θ_{JB}	11 ³	°CW
Junction to case	—	θ_{JC}	7 ⁴	°CW
Junction to top of package	Natural convection	Ψ_{jt}	2 ^{1,5}	°CW

¹ θ_{JA} and Ψ_{jt} parameters are simulated in accordance with EIA/JESD Standard 51-2 for natural convection. Freescale recommends the use of θ_{JA} and power dissipation specifications in the system design to prevent device junction temperatures from exceeding the rated specification. System designers should be aware that device junction temperatures can be significantly influenced by board layout and surrounding devices. Conformance to the device junction temperature specification can be verified by physical measurement in the customer's system using the Ψ_{jt} parameter, the device power dissipation, and the method described in EIA/JESD Standard 51-2.

² Per JEDEC JESD51-6 with the board horizontal.

³ Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

⁴ Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).

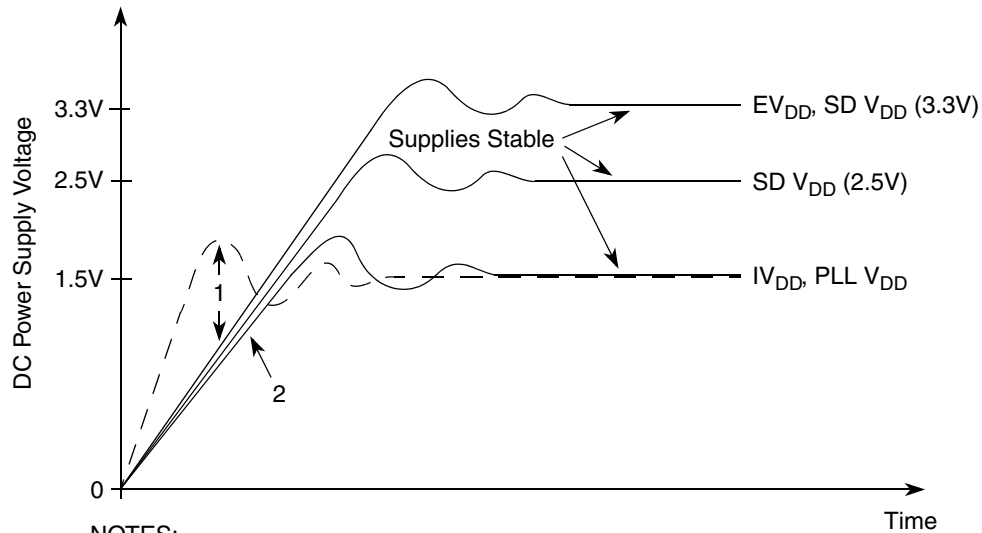
⁵ Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

3 DC Electrical Specifications

Table 4 lists DC electrical operating temperatures. This table is based on an operating voltage of $EV_{DD} = 3.3 V_{DC} \pm 0.3 V_{DC}$ and IV_{DD} of $1.5 \pm 0.07 V_{DC}$.

Table 4. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Units
External (I/O pads) operation voltage range	EV_{DD}	3.0	3.6	V
Memory (I/O pads) operation voltage range (DDR Memory)	$SD V_{DD}$	2.30	2.70	V
Internal logic operation voltage range ¹	IV_{DD}	1.43	1.58	V
PLL Analog operation voltage range ¹	$PLL V_{DD}$	1.43	1.58	V
USB oscillator operation voltage range	USB_OSV_{DD}	3.0	3.6	V
USB digital logic operation voltage range	$USBV_{DD}$	3.0	3.6	V
USB PHY operation voltage range	USB_PHYV_{DD}	3.0	3.6	V
USB oscillator analog operation voltage range	USB_OSCAV_{DD}	1.43	1.58	V


NOTES:

1. IV_{DD} should not exceed EV_{DD} or $SD V_{DD}$ by more than 0.4V at any time, including power-up.
2. Recommended that $IV_{DD}/PLL V_{DD}$ should track $EV_{DD}/SD V_{DD}$ up to 0.9V, then separate for completion of ramps.
3. Input voltage must not be greater than the supply voltage (EV_{DD} , $SD V_{DD}$, IV_{DD} , or $PLL V_{DD}$) by more than 0.5V at any time, including during power-up.
4. Use 1 microsecond or slower rise time for all supplies.

Figure 3. Supply Voltage Sequencing and Separation Cautions

The relationship between $SD V_{DD}$ and EV_{DD} is non-critical during power-up and power-down sequences. $SD V_{DD}$ (2.5V or 3.3V) and EV_{DD} are specified relative to IV_{DD} .

4.2.1 Power Up Sequence

If $EV_{DD}/SD V_{DD}$ are powered up with the IV_{DD} at 0V, the sense circuits in the I/O pads cause all pad output drivers connected to the $EV_{DD}/SD V_{DD}$ to be in a high impedance state. There is no limit to how long after $EV_{DD}/SD V_{DD}$ powers up before IV_{DD} must power up. IV_{DD} should not lead the EV_{DD} , $SD V_{DD}$, or $PLL V_{DD}$ by more than 0.4V during power ramp up or there is high current in the internal ESD protection diodes. The rise times on the power supplies should be slower than 1 microsecond to avoid turning on the internal ESD protection clamp diodes.

The recommended power up sequence is as follows:

1. Use 1 microsecond or slower rise time for all supplies.
2. $IV_{DD}/PLL V_{DD}$ and $EV_{DD}/SD V_{DD}$ should track up to 0.9V, then separate for the completion of ramps with $EV_{DD}/SD V_{DD}$ going to the higher external voltages. One way to accomplish this is to use a low drop-out voltage regulator.

4.2.2 Power Down Sequence

If $IV_{DD}/PLL V_{DD}$ are powered down first, sense circuits in the I/O pads cause all output drivers to be in a high impedance state. There is no limit on how long after IV_{DD} and $PLL V_{DD}$ power down before EV_{DD} or $SD V_{DD}$ must power down. IV_{DD} should not lag EV_{DD} , $SD V_{DD}$, or $PLL V_{DD}$ going low by more than 0.4V during power down or there is undesired high current in the ESD protection diodes. There are no requirements for the fall times of the power supplies.

The recommended power down sequence is as follows:

1. Drop $IV_{DD}/PLL V_{DD}$ to 0V
2. Drop $EV_{DD}/SD V_{DD}$ supplies

4.3 General USB Layout Guidelines

4.3.1 USB D+ and D- High-Speed Traces

1. High speed clock and the USBD+ and USBD- differential pair should be routed first.
2. Route USBD+ and USBD- signals on the top layer of the board.
3. The trace width and spacing of the USBD+ and USBD- signals should be such that the differential impedance is 90Ω .
4. Route traces over continuous planes (power and ground)—they should not pass over any power/ground plane slots or anti-etch. When placing connectors, make sure the ground plane clear-outs around each pin have ground continuity between all pins.
5. Maintain the parallelism (skew matched) between USBD+ and USBD-. These traces should be the same overall length.
6. Do not route USBD+ and USBD- traces under oscillators or parallel to clock traces and/or data buses. Minimize the lengths of high speed signals that run parallel to the USBD+ and USBD- pair. Maintain a minimum 50mil spacing to clock signals.
7. Keep USBD+ and USBD- traces as short as possible.
8. Route USBD+, USBD-, and USBVBUS signals with a minimum amount of vias and corners. Use 45° turns.
9. Stubs should be avoided as much as possible. If they cannot be avoided, stubs should be no greater than 200mils.

4.3.2 USB VBUS Traces

Connecting the USBVBUS pin directly to the 5V VBUS signal from the USB connector can cause long-term reliability problems in the ESD network of the processor. Therefore, use of an external voltage divider for VBUS is recommended. [Figure 4](#) and [Figure 5](#) depict possible connections for VBUS. Point A, marked in each figure, is where a 5V version of VBUS should connect. Point B, marked in each figure, is where a 3.3V version of VBUS should connect to the USBVBUS pin on the device.

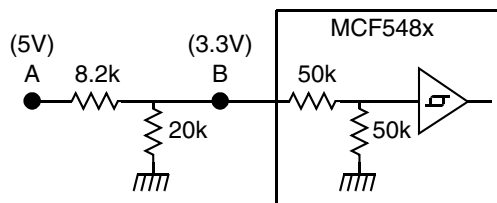


Figure 4. Preferred VBUS Connections

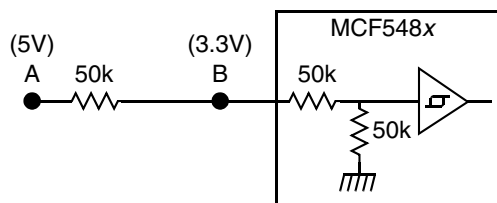


Figure 5. Alternate VBUS Connections

4.3.3 USB Receptacle Connections

It is recommended to connect the shield and the ground pin of the B USB receptacle for upstream ports to the board ground plane. The ground pin of the A USB receptacles for downstream ports should also be connected to the board ground plane, but industry practice varies widely on the connection of the shield of the A USB receptacles to other system grounds. Take precautions for control of ground loops between hosts and self-powered USB devices through the cable shield.

4.4 USB Power Filtering

To minimize noise, an external filter is required for each of the USB power pins. The filter shown in [Figure 6](#) should be connected between the board EV_{DD} or IV_{DD} and each of the USB V_{DD} pins.

- The resistor and capacitors should be placed as close to the dedicated USB V_{DD} pin as possible.
- A separate filter circuit should be included for each USB V_{DD} pin, a total of five circuits.
- All traces should be as low impedance as possible, especially ground pins to the ground plane.
- The filter for USB_PHYVDD to VSS should be connected to the power and ground planes, respectively, not fingers of the planes.
- In addition to keeping the filter components for the USB_PLLVDD as close as practical to the body of the processor as previously mentioned, special care should be taken to avoid coupling switching power supply noise or digital switching noise onto the portion of that supply between the filter and the processor.
- The capacitors for C2 in the table below should be rated X5R or better due to temperature performance.

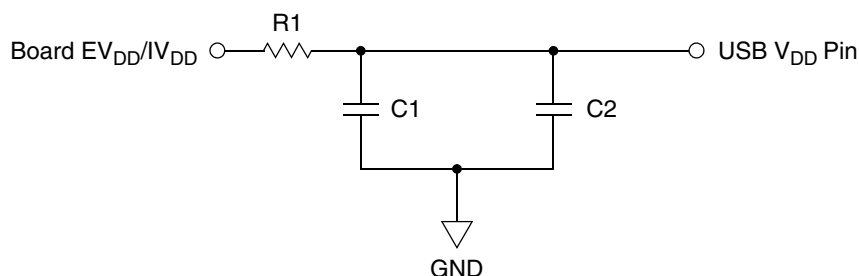


Figure 6. USB V_{DD} Power Filter

NOTE

In addition to the above filter circuitry, a 0.01 F capacitor is also recommended in parallel with those shown.

[Table 5](#) lists the resistor values and supply voltages to be used in the circuit for each of the USB V_{DD} pins.

Table 5. USB Filter Circuit Values

USB V_{DD} Pin	Nominal Voltage	R1 (Ω)	C1 (μ F)	C2 (μ F)
USBVDD (Bias generator supply)	3.3V	10	10	0.1
USB_PHYVDD (Main transceiver supply)	3.3V	0	10	0.1
USB_PLLVDD (PLL supply)	1.5V	10	1	0.1
USB_OSCVDD (Oscillator supply)	3.3V	0	10	0.1
USB_OSCAVDD (Oscillator analog supply)	1.5V	0	10	0.1

4.4.1 Bias Resistor

The USBRBIAS resistor should be placed as close to the dedicated USB 2.0 pins as possible. The tolerance should be $\pm 1\%$.

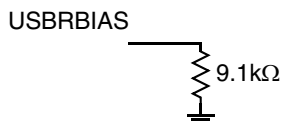


Figure 7. USBRBIAS Connection

5 Output Driver Capability and Loading

Table 6 lists values for drive capability and output loading.

Table 6. I/O Driver Capability¹

Signal	Drive Capability	Output Load (C _L)
SDRAMC (SDADDR[12:0], SDDATA[31:0], \overline{RAS} , \overline{CAS} , SDDM[3:0], \overline{SDWE} , SDBA[1:0])	24 mA	15 pF
SDRAMC DQS and clocks (SDDQS[3:0], SDRDQS, SDCLK[1:0], \overline{SDCLK} [1:0], SDCKE)	24 mA	15 pF
SDRAMC chip selects (\overline{SDCS} [3:0])	24 mA	15 pF
FlexBus (AD[31:0], \overline{FBCS} [5:0], ALE, R/\overline{W} , $\overline{BE}/\overline{BWE}$ [3:0], \overline{OE})	16 mA	30 pF
FEC (EnMDIO, EnMDC, EnTXEN, EnTXD[3:0], EnTXER)	8 mA	15 pF
Timer (TOUT[3:0])	8 mA	50 pF
FlexCAN (CANTX)	8 mA	30 pF
\overline{DACK} [1:0]	8 mA	30 pF
PSC (PSCnTXD[3:0], $\overline{PSCnRTS}/\overline{PSCnFSYNC}$,	8 mA	30 pF
DSPI (DSPISOUT, DSPICS0/SS, DSPICS[2:3], DSPICS5/PCSS)	24 mA	50 pF
PCI (PCIAD[31:0], PCIBG[4:1], PCIBG0/PCIREQOUT, PCIDEVSEL, PCICXBE[3:0], PCIFRM, PCIPERR, PCIRESET, PCISERR, PCISTOP, PCIPAR, PCITRDY, PCIIRDY)	16 mA	50 pF
I2C (SCL, SDA)	8 mA	50 pF
BDM (PSTCLK, PSTDDATA[7:0], DSO/TDO,	8 mA	25 pF
RSTO	8 mA	50 pF

¹ The device's pads have balanced sink and source current. The drive capability is the same as the sink capability.

7 Reset Timing Specifications

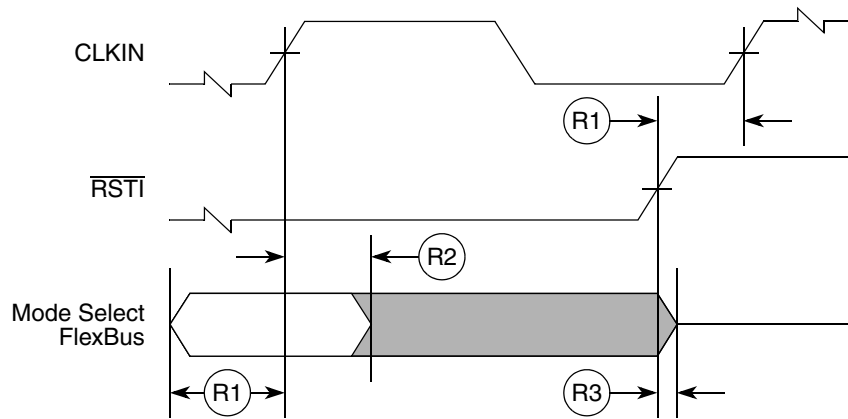
Table 9 lists specifications for the reset timing parameters shown in Figure 10

Table 9. Reset Timing Specifications

Num	Characteristic	50 MHz CLKIN		Units
		Min	Max	
R1 ¹	Valid to CLKIN (setup)	8	—	ns
R2	CLKIN to invalid (hold)	1.0	—	ns
R3	$\overline{\text{RSTI}}$ to invalid (hold)	1.0	—	ns
	$\overline{\text{RSTI}}$ pulse duration	5	—	CLKIN cycles

¹ $\overline{\text{RSTI}}$ and FlexBus data lines are synchronized internally. Setup and hold times must be met only if recognition on a particular clock is required.

Figure 10 shows reset timing for the values in Table 9.



NOTE:
Mode selects are registered on the rising clock edge before the cycle in which $\overline{\text{RSTI}}$ is recognized as being negated.

Figure 10. Reset Timing

8 FlexBus

A multi-function external bus interface called FlexBus is provided on the MCF5482 with basic functionality to interface to slave-only devices up to a maximum bus frequency of 66 MHz. It can be directly connected to asynchronous or synchronous devices such as external boot ROMs, flash memories, gate-array logic, or other simple target (slave) devices with little or no additional circuitry. For asynchronous devices, a simple chip-select based interface can be used. The FlexBus interface has six general purpose chip-selects ($\overline{\text{FBCS}}[5:0]$). Chip-select $\overline{\text{FBCS0}}$ can be dedicated to boot ROM access and can be programmed to be byte (8 bits), word (16 bits), or longword (32 bits) wide. Control signal timing is compatible with common ROM / flash memories.

8.1 FlexBus AC Timing Characteristics

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the system clock.

Table 10. FlexBus AC Timing Specifications

Num	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	25	50	Mhz	¹
FB1	Clock Period (CLKIN)	20	40	ns	²
FB2	Address, Data, and Control Output Valid (AD[31:0], $\overline{\text{FBCS}}[5:0]$, R/W, ALE, TSIZ[1:0], $\overline{\text{BE}}/\overline{\text{BWE}}[3:0]$, $\overline{\text{OE}}$, and $\overline{\text{TBST}}$)	—	7.0	ns	³
FB3	Address, Data, and Control Output Hold ((AD[31:0], $\overline{\text{FBCS}}[5:0]$, R/W, ALE, TSIZ[1:0], $\overline{\text{BE}}/\overline{\text{BWE}}[3:0]$, $\overline{\text{OE}}$, and $\overline{\text{TBST}}$)	1	—	ns	^{3, 4}
FB4	Data Input Setup	3.5	—	ns	
FB5	Data Input Hold	0	—	ns	
FB6	Transfer Acknowledge ($\overline{\text{TA}}$) Input Setup	4	—	ns	
FB7	Transfer Acknowledge ($\overline{\text{TA}}$) Input Hold	0	—	ns	
FB8	Address Output Valid (PCIAD[31:0])	—	7.0	ns	⁵
FB9	Address Output Hold (PCIAD[31:0])	0	—	ns	⁵

¹ The frequency of operation is the same as the PCI frequency of operation. The MCF548X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI.

² Max cycle rate is determined by CLKIN and how the user has the system PLL configured.

³ Timing for chip selects only applies to the $\overline{\text{FBCS}}[5:0]$ signals. Please see [Section 9.2, “DDR SDRAM AC Timing Characteristics”](#) for $\overline{\text{SDCS}}[3:0]$ timing.

⁴ The FlexBus supports programming an extension of the address hold. Please consult the MCF548X specification manual for more information.

⁵ These specs are used when the PCIAD[31:0] signals are configured as 32-bit, non-muxed FlexBus address signals.

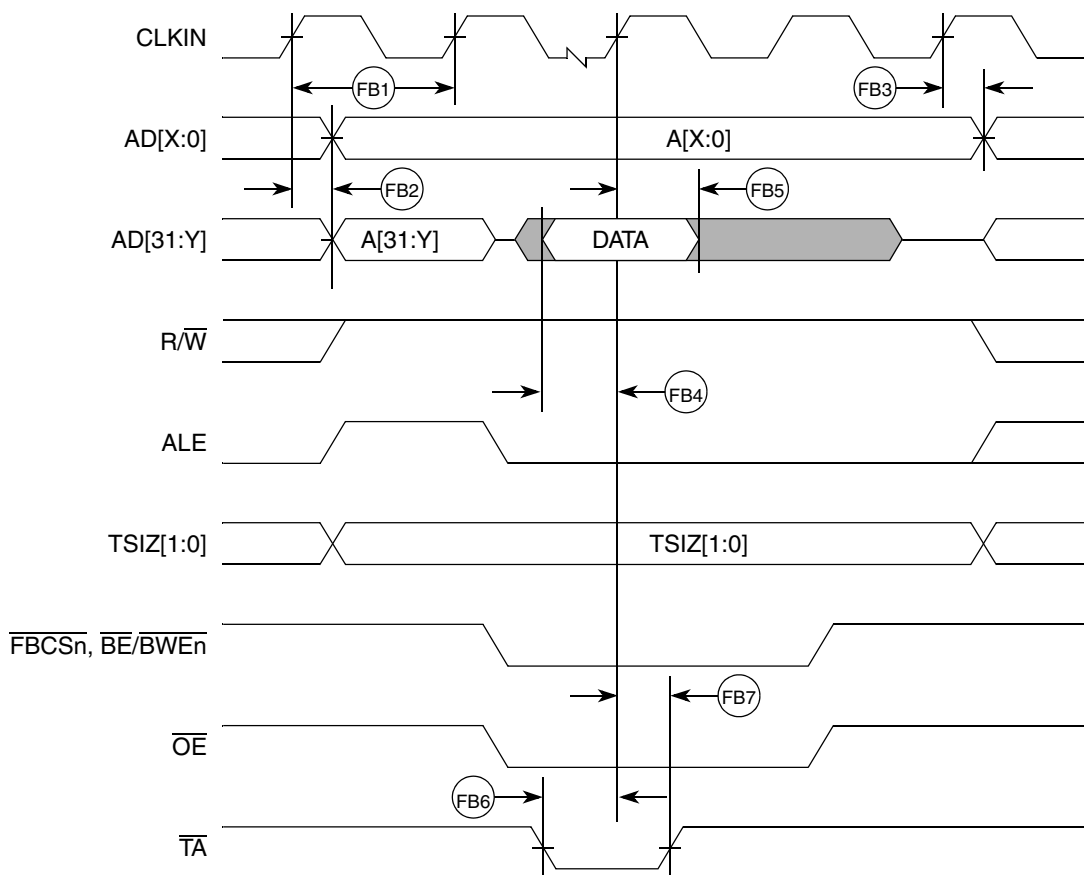


Figure 11. FlexBus Read Timing

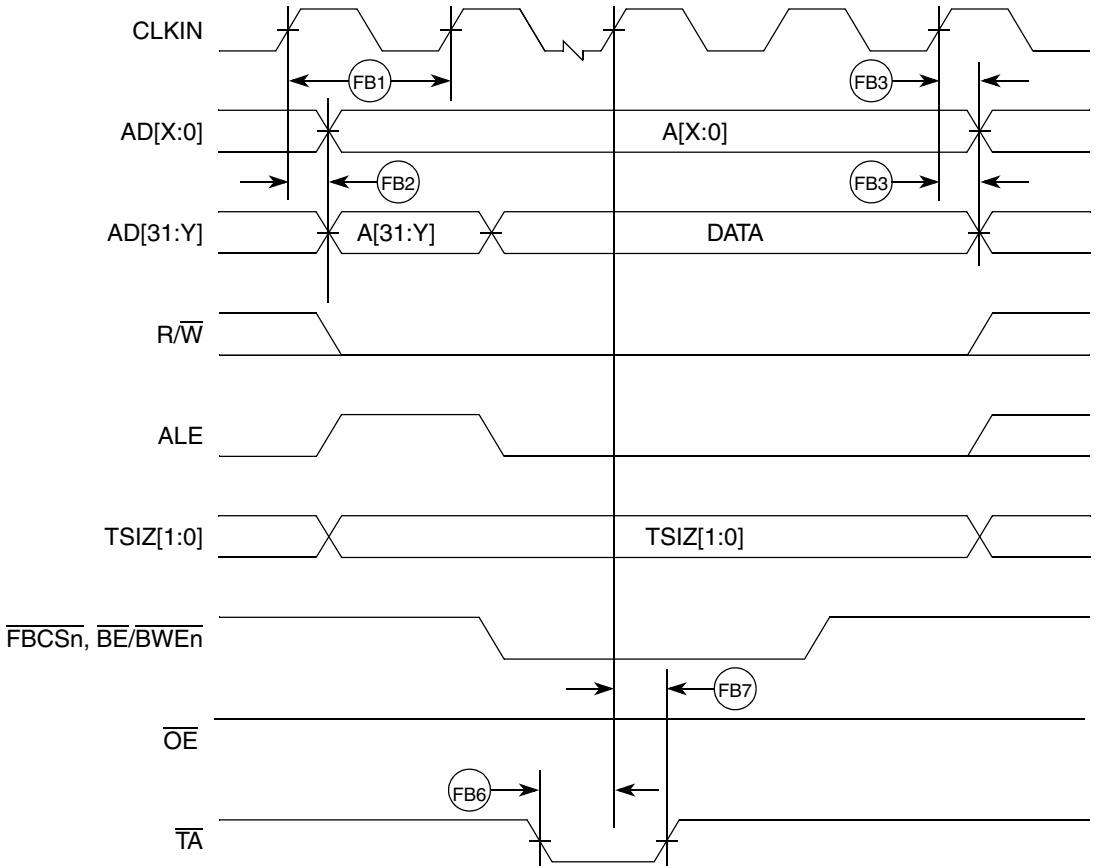


Figure 12. FlexBus Write Timing

9 SDRAM Bus

The SDRAM controller supports accesses to main SDRAM memory from any internal master. It supports standard SDRAM or double data rate (DDR) SDRAM, but it does not support both at the same time. The SDRAM controller uses SSTL2 and SSTL3 I/O drivers. Both SSTL drive modes are programmable for Class I or Class II drive strength.

9.1 SDR SDRAM AC Timing Characteristics

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the memory bus clock, when operating in SDR mode on write cycles and relative to SDR_DQS on read cycles. The MCF548x SDRAM controller is a DDR controller that has an SDR mode. Because it is designed to support DDR, a DQS pulse must be supplied to the MCF548x for each data beat of an SDR read. The MCF548x accomplishes this by asserting a signal called SDR_DQS during read cycles. Care must be taken during board design to adhere to the following guidelines and specs with regard to the SDR_DQS signal and its usage.

Table 13. DDR Timing Specifications (continued)

Symbol	Characteristic	Min	Max	Unit	Notes
DD13	DQS input read preamble width (t_{RPRE})	0.9	1.1	SDCLK	
DD14	DQS input read postamble width (t_{RPST})	0.4	0.6	SDCLK	
DD15	DQS output write preamble width (t_{WPRE})	0.25	—	SDCLK	
DD16	DQS output write postamble width (t_{WPST})	0.4	0.6	SDCLK	

- ¹ DDR memories typically have a minimum speed specification of 83 MHz. Check memory component specifications to verify.
- ² The frequency of operation is 2x or 4x the CLKIN frequency of operation. The MCF548X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI, but SDRAM clock operates at the same frequency as the internal bus clock. Please see the reset configuration signals description in the “Signal Descriptions” chapter within the *MCF548x Reference Manual*.
- ³ SDCLK is one memory clock in (ns).
- ⁴ Pulse width high plus pulse width low cannot exceed max clock period.
- ⁵ Pulse width high plus pulse width low cannot exceed max clock period.
- ⁶ Command output valid should be 1/2 the memory bus clock (SDCLK) plus some minor adjustments for process, temperature, and voltage variations.
- ⁷ This specification relates to the required input setup time of today’s DDR memories. SDDATA[31:24] is relative to SDDQS3, SDDATA[23:16] is relative to SDDQS2, SDDATA[15:8] is relative to SDDQS1, and SDDATA[7:0] is relative SDDQS0.
- ⁸ The first data beat is valid before the first rising edge of SDDQS and after the SDDQS write preamble. The remaining data beats is valid for each subsequent SDDQS edge.
- ⁹ This specification relates to the required hold time of today’s DDR memories. SDDATA[31:24] is relative to SDDQS3, SDDATA[23:16] is relative to SDDQS2, SDDATA[15:8] is relative to SDDQS1, and SDDATA[7:0] is relative SDDQS0.
- ¹⁰ Data input skew is derived from each SDDQS clock edge. It begins with a SDDQS transition and ends when the last data line becomes valid. This input skew must include DDR memory output skew and system level board skew (due to routing or other factors).
- ¹¹ Data input hold is derived from each SDDQS clock edge. It begins with a SDDQS transition and ends when the first data line becomes invalid.

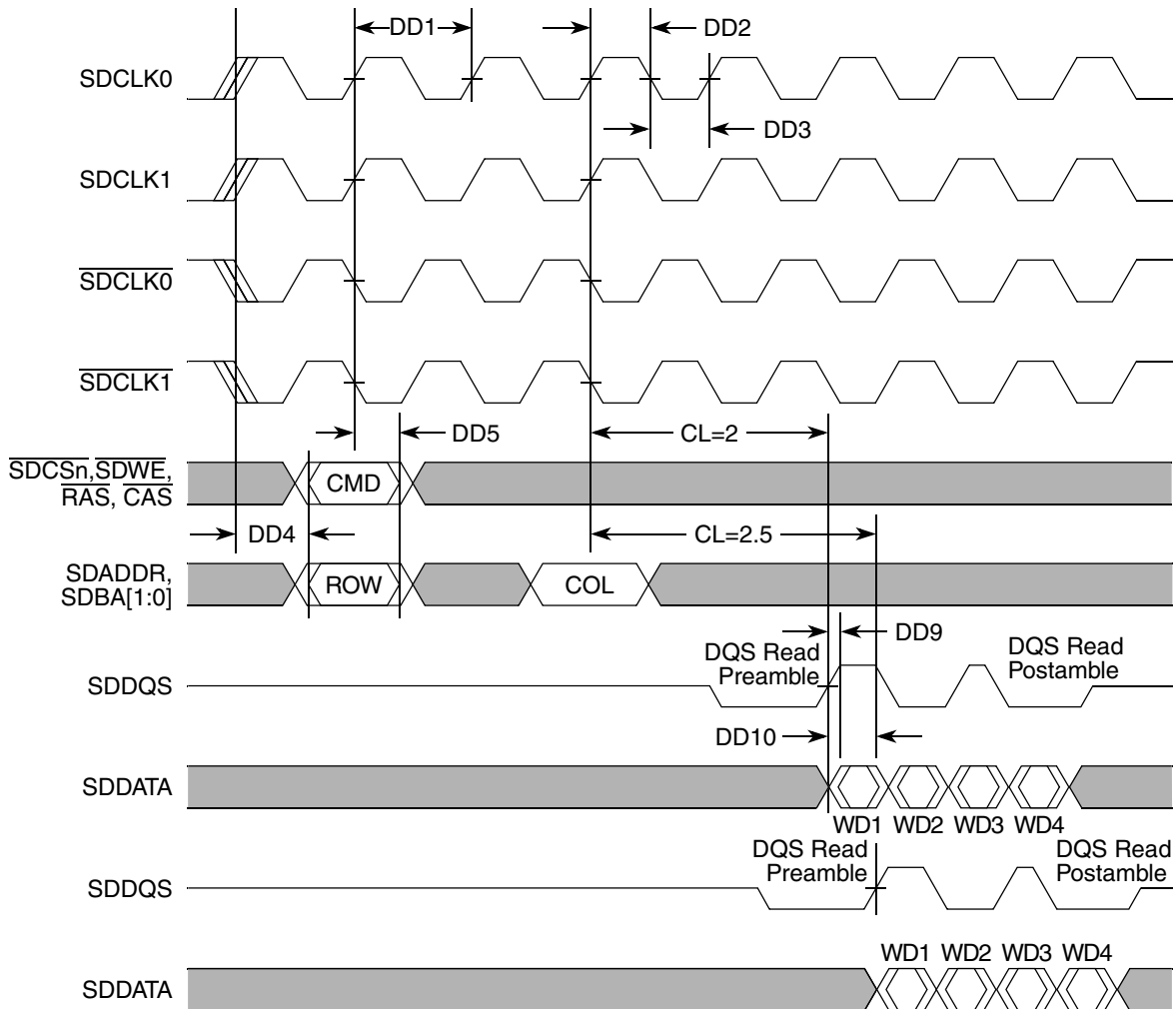


Figure 17. DDR Read Timing

10 PCI Bus

The PCI bus on the MCF548x is PCI 2.2 compliant. The following timing numbers are mostly from the PCI 2.2 spec. Please refer to the PCI 2.2 spec for a more detailed timing analysis.

Table 14. PCI Timing Specifications

Num	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	25	50	MHz	1
P1	Clock Period (t_{CK})	20	40	ns	2
P2	Address, Data, and Command ($33 < \text{PCI} \leq 50 \text{ Mhz}$)—Input Setup (t_{IS})	3.0	—	ns	
P3	Address, Data, and Command ($0 < \text{PCI} \leq 33 \text{ Mhz}$)—Input Setup (t_{IS})	7.0	—	ns	
P4	Address, Data, and Command ($33\text{--}50 \text{ Mhz}$)—Output Valid (t_{DV})	—	6.0	ns	3
P5	Address, Data, and Command ($0\text{--}33 \text{ Mhz}$) - Output Valid (t_{DV})	—	11.0	ns	
P6	PCI signals ($0\text{--}50 \text{ Mhz}$) - Output Hold (t_{DH})	0	—	ns	4

Table 14. PCI Timing Specifications (continued)

Num	Characteristic	Min	Max	Unit	Notes
P7	PCI signals (0–50 Mhz) - Input Hold (t_{IH})	0	—	ns	5
P8	PCI REQ/GNT ($33 < \text{PCI} \leq 50\text{Mhz}$) - Output valid (t_{DV})	—	6	ns	6
P9	PCI REQ/GNT ($0 < \text{PCI} \leq 33\text{Mhz}$) - Output valid (t_{DV})	—	12	ns	
P10	PCI REQ/GNT ($33 < \text{PCI} \leq 50\text{Mhz}$) - Input Setup (t_{IS})	—	5	ns	
P11	PCI REQ ($0 < \text{PCI} \leq 33\text{Mhz}$) - Input Setup (t_{IS})	12	—	ns	
P12	PCI GNT ($0 < \text{PCI} \leq 33\text{Mhz}$) - Input Setup (t_{IS})	10	—	ns	

- ¹ Please see the reset configuration signals description in the “Signal Descriptions” chapter within the *MCF548x Reference Manual*. Also specific guidelines may need to be followed when operating the system PLL below certain frequencies.
- ² Max cycle rate is determined by CLKIN and how the user has the system PLL configured.
- ³ All signals defined as PCI based signals. Does not include PTP (point-to-point) signals.
- ⁴ PCI 2.2 spec does not require an output hold time. Although the MCF548X may provide a slight amount of hold, it is not required or guaranteed.
- ⁵ PCI 2.2 spec requires zero input hold.
- ⁶ These signals are defined at PTP (Point-to-point) in the PCI 2.2 spec.

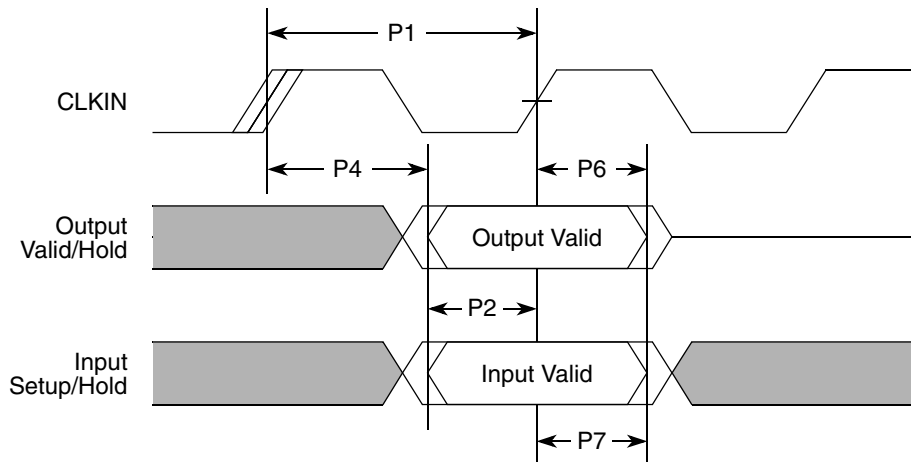


Figure 18. PCI Timing

11 Fast Ethernet AC Timing Specifications

11.1 MII/7-WIRE Interface Timing Specs

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the EMAC_10_100 I/O signals.

The following timing specs meet the requirements for MII and 7-Wire style interfaces for a range of transceiver devices. If this interface is to be used with a specific transceiver device the timing specs may be altered to match that specific transceiver.

12 General Timing Specifications

Table 19 lists timing specifications for the GPIO, PSC, FlexCAN, \overline{DREQ} , \overline{DACK} , and external interrupts.

Table 19. General AC Timing Specifications

Name	Characteristic	Min	Max	Unit
G1	CLKIN high to signal output valid	—	2	PSTCLK
G2	CLKIN high to signal invalid (output hold)	0	—	ns
G3	Signal input pulse width	2	—	PSTCLK

13 I²C Input/Output Timing Specifications

Table 20 lists specifications for the I²C input timing parameters shown in Figure 23.

Table 20. I²C Input Timing Specifications between SCL and SDA

Num	Characteristic	Min	Max	Units
I1	Start condition hold time	2	—	Bus clocks
I2	Clock low period	8	—	Bus clocks
I3	SCL/SDA rise time ($V_{IL} = 0.5\text{ V}$ to $V_{IH} = 2.4\text{ V}$)	—	1	mS
I4	Data hold time	0	—	ns
I5	SCL/SDA fall time ($V_{IH} = 2.4\text{ V}$ to $V_{IL} = 0.5\text{ V}$)	—	1	mS
I6	Clock high time	4	—	Bus clocks
I7	Data setup time	0	—	ns
I8	Start condition setup time (for repeated start condition only)	2	—	Bus clocks
I9	Stop condition setup time	2	—	Bus clocks

Table 21 lists specifications for the I²C output timing parameters shown in Figure 23.

Table 21. I²C Output Timing Specifications between SCL and SDA

Num	Characteristic	Min	Max	Units
I1 ¹	Start condition hold time	6	—	Bus clocks
I2 ¹	Clock low period	10	—	Bus clocks
I3 ²	SCL/SDA rise time ($V_{IL} = 0.5\text{ V}$ to $V_{IH} = 2.4\text{ V}$)	—	—	μS
I4 ¹	Data hold time	7	—	Bus clocks
I5 ³	SCL/SDA fall time ($V_{IH} = 2.4\text{ V}$ to $V_{IL} = 0.5\text{ V}$)	—	3	ns
I6 ¹	Clock high time	10	—	Bus clocks
I7 ¹	Data setup time	2	—	Bus clocks
I8 ¹	Start condition setup time (for repeated start condition only)	20	—	Bus clocks
I9 ¹	Stop condition setup time	10	—	Bus clocks

JTAG and Boundary Scan Timing

- ¹ Output numbers depend on the value programmed into the IFDR; an IFDR programmed with the maximum frequency (IFDR = 0x20) results in minimum output timings as shown in Table 21. The I²C interface is designed to scale the actual data transition time to move it to the middle of the SCL low period. The actual position is affected by the prescale and division values programmed into the IFDR; however, the numbers given in Table 21 are minimum values.
- ² Because SCL and SDA are open-collector-type outputs, which the processor can only actively drive low, the time SCL or SDA take to reach a high level depends on external signal capacitance and pull-up resistor values.
- ³ Specified at a nominal 50-pF load.

Figure 23 shows timing for the values in Table 20 and Table 21.

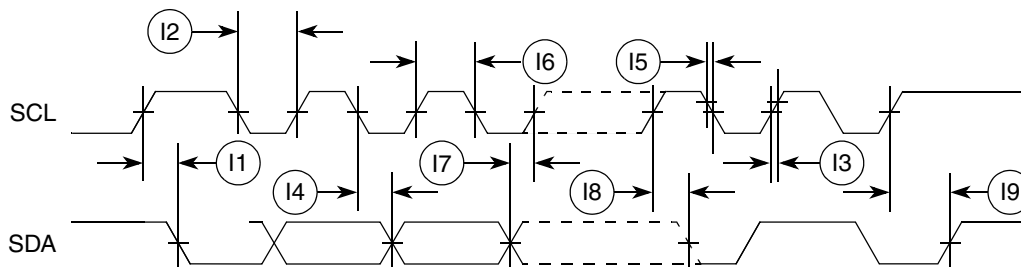


Figure 23. I²C Input/Output Timings

14 JTAG and Boundary Scan Timing

Table 22. JTAG and Boundary Scan Timing

Num	Characteristics ¹	Symbol	Min	Max	Unit
J1	TCLK Frequency of Operation	f_{JCYC}	DC	10	MHz
J2	TCLK Cycle Period	t_{JCYC}	2	—	t_{CK}
J3	TCLK Clock Pulse Width	t_{JCW}	15.15	—	ns
J4	TCLK Rise and Fall Times	t_{JCRF}	0.0	3.0	ns
J5	Boundary Scan Input Data Setup Time to TCLK Rise	t_{BSDST}	5.0	—	ns
J6	Boundary Scan Input Data Hold Time after TCLK Rise	t_{BSDHT}	24.0	—	ns
J7	TCLK Low to Boundary Scan Output Data Valid	t_{BSDV}	0.0	15.0	ns
J8	TCLK Low to Boundary Scan Output High Z	t_{BSDZ}	0.0	15.0	ns
J9	TMS, TDI Input Data Setup Time to TCLK Rise	t_{TAPBST}	5.0	—	ns
J10	TMS, TDI Input Data Hold Time after TCLK Rise	t_{TAPBHT}	10.0	—	ns
J11	TCLK Low to TDO Data Valid	t_{TDODV}	0.0	20.0	ns
J12	TCLK Low to TDO High Z	t_{TDODZ}	0.0	15.0	ns
J13	\overline{TRST} Assert Time	t_{TRSTAT}	100.0	—	ns
J14	\overline{TRST} Setup Time (Negation) to TCLK High	t_{TRSTST}	10.0	—	ns

¹ MTMOD is expected to be a static signal. Hence, it is not associated with any timing

Table 23 lists specifications for the debug AC timing parameters shown in Figure 29.

Table 23. Debug AC Timing Specifications

Num	Characteristic	50 MHz		Units
		Min	Max	
D1	PSTDDATA to PSTCLK setup	4.5	—	ns
D2	PSTCLK to PSTDDATA hold	4.5	—	ns
D3	DSI-to-DSCLK setup	1	—	PSTCLKs
D4 ¹	DSCLK-to-DSO hold	4	—	PSTCLKs
D5	DSCLK cycle time	5	—	PSTCLKs

¹ DSCLK and DSI are synchronized internally. D4 is measured from the synchronized DSCLK input relative to the rising edge of CLKOUT.

Figure 28 shows real-time trace timing for the values in Table 23.

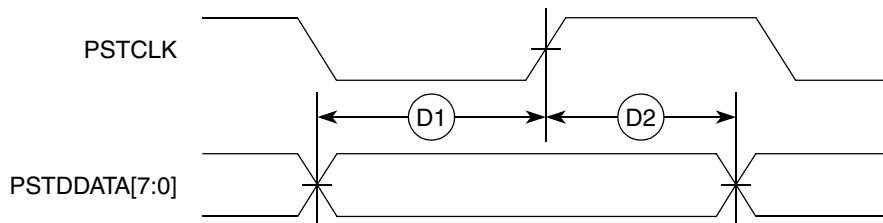


Figure 28. Real-Time Trace AC Timing

Figure 29 shows BDM serial port AC timing for the values in Table 23.

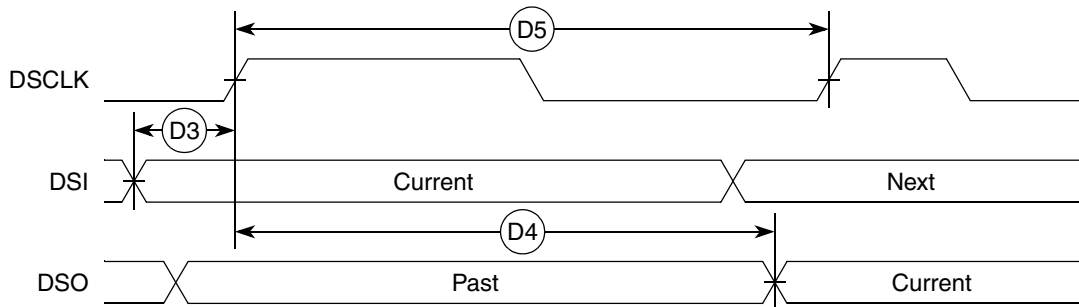


Figure 29. BDM Serial Port AC Timing

15 DSPI Electrical Specifications

Table 24 lists DSPI timings.

Table 24. DSPI Modules AC Timing Specifications

Name	Characteristic	Min	Max	Unit
DS1	DSPI_CS[3:0] to DSPI_CLK	$1 \times t_{ck}$	$510 \times t_{ck}$	ns
DS2	DSPI_CLK high to DSPI_DOUT valid.	—	12	ns
DS3	DSPI_CLK high to DSPI_DOUT invalid. (Output hold)	2	—	ns
DS4	DSPI_DIN to DSPI_CLK (Input setup)	10	—	ns
DS5	DSPI_DIN to DSPI_CLK (Input hold)	10	—	ns

The values in Table 24 correspond to Figure 30.

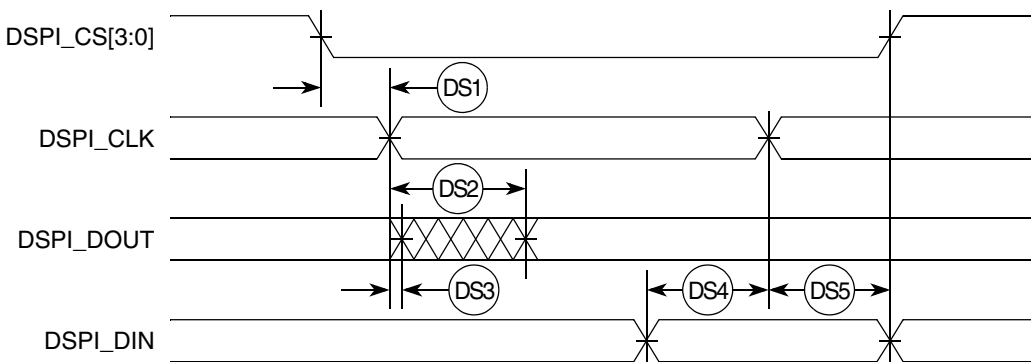


Figure 30. DSPI Timing

16 Timer Module AC Timing Specifications

Table 25 lists timer module AC timings.

Table 25. Timer Module AC Timing Specifications

Name	Characteristic	0–50 MHz		Unit
		Min	Max	
T1	TIN0 / TIN1 / TIN2 / TIN3 cycle time	3	—	PSTCLK
T2	TIN0 / TIN1 / TIN2 / TIN3 pulse width	1	—	PSTCLK

18 Revision History

Revision Number	Date	Substantive Changes
2.2	August 29, 2005	Table 7 : Changed C1 minimum spec from 15.15 ns to 20 ns and maximum spec from 33.3 ns to 40 ns.
2.3	August 30, 2005	Table 22 : Changed J11 maximum from 15 ns to 20 ns.
2.4	December 14, 2005	<p>Table 9: Changed heading maximum from 66 MHz to 50 MHz.</p> <p>Table 10: Changed frequency of operation maximum from 66 MHz to 50 MHz and corresponding FB1 minimum from 15.15 ns to 20 ns.</p> <p>Table 10: Changed FB1 maximum from 33.33 ns to 40 ns.</p> <p>Table 14: Changed frequency of operation maximum from 66 MHz to 50 MHz and corresponding FB1 minimum from 15.15 ns to 20 ns.</p> <p>Table 14: Changed FB1 maximum from 33.33 ns to 40 ns.</p> <p>Table 14: Changed various entry descriptions from “(33 < PCI ≤ 66 Mhz)” to (33 < PCI ≤ 50 Mhz)</p> <p>Table 23: Changed heading maximum from 66 MHz to 50 MHz.</p> <p>Table 25: Changed heading maximum from 66 MHz to 50 MHz.</p>
3	February 20, 2007	<p>Table 4: Updated DC electrical specifications, V_{IL} and V_{IH}.</p> <p>Table 6: Changed FlexBus output load from 20pF to 30pF.</p> <p>Added Section 4.3, “General USB Layout Guidelines.”</p>
4	December 4, 2007	<p>Figure 2: Changed resistor value from 10W to 10Ω</p> <p>Figure 3: Changed note 1 in from “IVDD should not exceed EVDD, SD VDD or PLL VDD by more than 0.4V...” to “IVDD should not exceed EVDD or SD VDD by more than 0.4V...”</p> <p>Table 3: Updated thermal information for θ_{JMA}, θ_{JB}, and θ_{JC}</p> <p>Table 4: Added input leakage current spec.</p> <p>Table 6: Added footnote regarding pads having balanced source & sink current.</p> <p>Table 9: Added \overline{RSTI} pulse duration spec.</p> <p>Added features list, pinout drawing, block diagram, and case outline.</p>

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